N-Channel 100-V (D-S) MOSFET

Key Features:

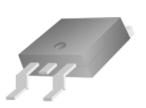
- Low r_{DS(on)} trench technology
- · Low thermal impedance
- · Fast switching speed

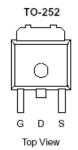
Tv	pical	Apr	olicat	tions:
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- · White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

PRODUCT SUMMARY					
V _{DS} (V)	$r_{DS(on)}(m\Omega)$	I _D (A)			
100	420 @ V _{GS} = 10V	9.0			
	460 @ V _{GS} = 5.5V	8.6			







ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}$ C UNLESS OTHERWISE NOTED)						
Parameter		Symbol	Limit	Units		
Drain-Source Voltage			100	V		
Gate-Source Voltage			±20	V		
Continuous Drain Current a	T _A =25°C	I _D	9.0	Α		
Pulsed Drain Current ^b		I _{DM}	50	Α		
Continuous Source Current (Diode Conduction) ^a			33.6	А		
Power Dissipation ^a	T _A =25°C	P_{D}	50	W		
Operating Junction and Storage Temperature Range		T_J, T_{stg}	-55 to 175	°C		

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Maximum	Units		
Maximum Junction-to-Ambient ^a	$R_{\theta JA}$	40	°C/W		
Maximum Junction-to-Case	$R_{\theta JC}$	3	C/VV		

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Electrical Characteristics

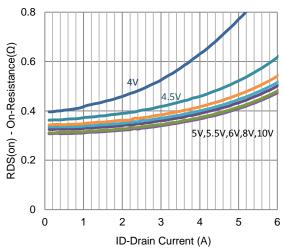
Parameter	Symbol	I Test Conditions		Тур	Max	Unit
Static						
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 250 \text{ uA}$	1			V
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA
Zoro Coto Voltogo Droin Current	1	$V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25	
On-State Drain Current	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	10			Α
Drain-Source On-Resistance	r	$V_{GS} = 10 \text{ V}, I_{D} = 5 \text{ A}$			420	mΩ
Dialii-Source Off-Resistance	r _{DS(on)}	$V_{GS} = 5.5 \text{ V}, I_D = 4.2 \text{ A}$			460	11122
Forward Transconductance	g _{fs}	$V_{DS} = 15 \text{ V}, I_{D} = 5 \text{ A}$		20		S
Diode Forward Voltage	V_{SD}	I _S = 16.8 A, V _{GS} = 0 V		1.21		V
Dynamic						
Total Gate Charge	Q_g	$V_{DS} = 50 \text{ V}, V_{GS} = 5.5 \text{ V},$		3.3		
Gate-Source Charge	Q_gs	$I_{DS} = 50 \text{ V}, \text{ V}_{GS} = 5.3 \text{ V},$ $I_{D} = 5 \text{ A}$		0.9		nC
Gate-Drain Charge	Q_gd	ID = 3 \(\Lambda\)		1.9		
Turn-On Delay Time	t _{d(on)}	$V_{DS} = 50 \text{ V}, R_1 = 10 \Omega,$		3		
Rise Time	t _r	$V_{DS} = 50 \text{ V}, R_L - 10 \Omega,$ $I_D = 5 \text{ A},$		7		no
Turn-Off Delay Time	$t_{d(off)}$	$V_{GEN} = 10 \text{ V}, R_{GEN} = 6 \Omega$		13		ns
Fall Time	t _f	V _{GEN} = 10 V, N _{GEN} = 0.22		5		
Input Capacitance	C _{iss}			176		
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		22		pF
Reverse Transfer Capacitance	C_{rss}			18		

Notes

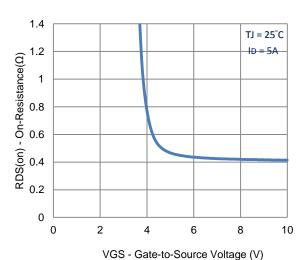
- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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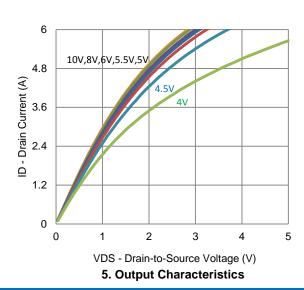
Typical Electrical Characteristics

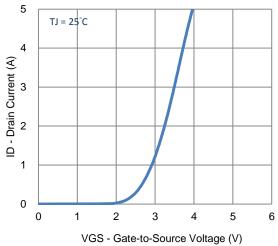


1. On-Resistance vs. Drain Current

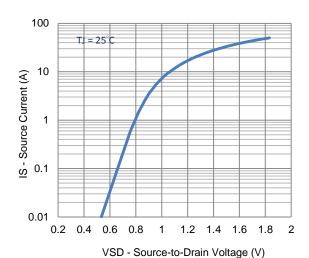


3. On-Resistance vs. Gate-to-Source Voltage

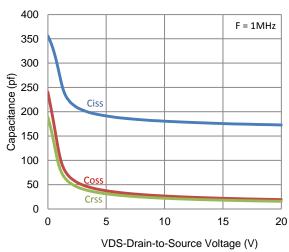




2. Transfer Characteristics

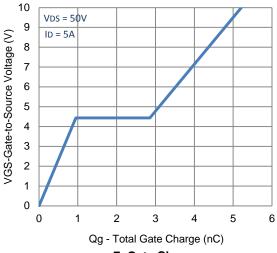


4. Drain-to-Source Forward Voltage

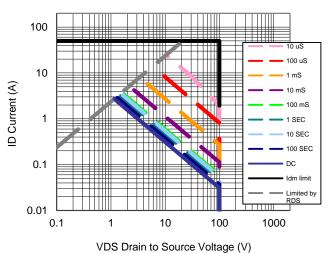


6. Capacitance

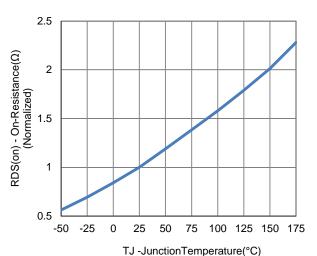
Typical Electrical Characteristics



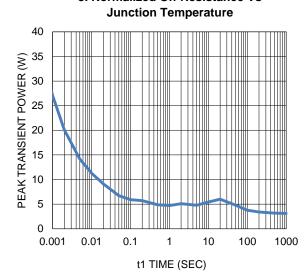




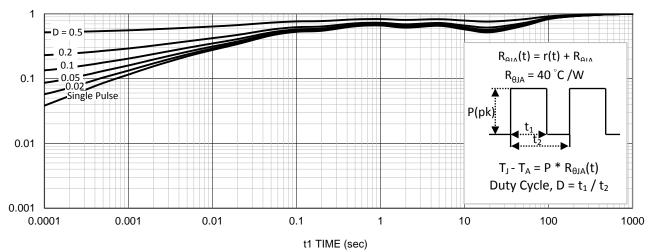
9. Safe Operating Area



8. Normalized On-Resistance Vs

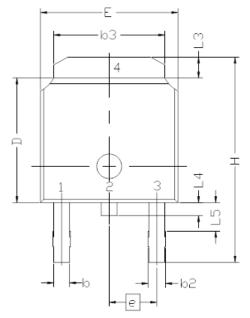


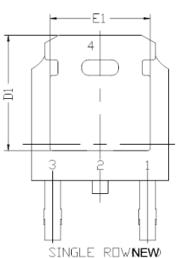
10. Single Pulse Maximum Power Dissipation

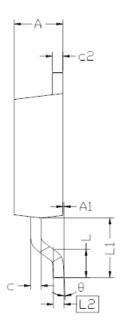


11. Normalized Thermal Transient Junction to Ambient

Package Information







SYMBOL	DIMENS: MIN	IONAL F Nom	REQMTS MAX
E	6.40	6.60	6.731
L	1.40	1.52	1.77
L1	2	.743 RE	F
L2	0.	.508 BS	:C
L3	0.89		1.27
L4	0.64		1.01
L5			
D	6.00	6.10	6.223
Н	9.40	10.00	10.40
b	0.64	0.76	0.88
b2	0.77	0.84	1.14
b3	5.21	5.34	5.46
е	2.	286 BS	
Α	2,20	2,30	2.38
A1	0		0.127
C	0.45	0.50	0.60
c2	0.45	0.50	0,58
D1	5,30		
E1	4.40		
θ	0°		10°

Note:

- 1. All Dimension Are In mm.
- 2. Package Body Sizes Exclude Mold Flash, Protrusion Or Gate Burrs. Mold Flash, Protrusion Or Gate Burrs Shall Not Exceed 0.10 mm Per Side.
- 3. Package Body Sizes Determined At The Outermost Extremes Of The Plastic Body Exclusive Of Mold Flash, Gate Burrs And Interlead Flash, But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.